



Compared to conventional SiPM, NDL SiPM employs an intrinsic epitaxial layer as the quenching resistors and uses a continuous silicon capping layer as an anode to connect all APD cells. Thus, the device has a more compact structure and simpler fabrication technology, which allows for a larger micro-cell density (larger dynamic range) while adequate PDE. Furthermore, NDL SiPM helps implement a two-dimensional (2D) position-sensitive (PS) SiPM, which has attractive advantages of fewer output electrodes, simple readout electronics and a high position resolution.

Features

- ◆ Simple Readout Electronics
- ◆ High Position Resolution
- ◆ Large Dynamic Range While High PDE
- ◆ Fast Rise Time and Short Pulse Width
- ◆ Short Recovery Time and High Time Resolution
- ◆ Cost Effective

Applications

- ◆ High Energy Physics
- ◆ LiDAR
- ◆ Nuclear Medical Imaging (PET, SPECT, CT)
- ◆ Radiation Detection and Imaging
- ◆ Optical Spectroscope
- ◆ Other Low Level Light Position-Sensitive Detection

Specifications

Type	PSS 11-3030-S	PSS 11-6060-S
Effective Pitch	10 μm	20 μm
Active Area	3.0×3.0 mm^2	6.24×6.24 mm^2
Micro-cell Number	10000 / mm^2	2500 / mm^2
Typical Breakdown Voltage (V_B)	26.5 V	27.5 V
Peak PDE @420nm	32 %	40 %
Recommended Operation Voltage	$V_B + 5 \text{ V}$	$V_B + 5 \text{ V}$
Gain	2.0×10^5	8.0×10^5
Dark Count Rate (DCR)	650 kHz / mm^2	150 kHz / mm^2
Configuration of Anodes	Tetra-Lateral Anodes	Square-Bordered Anodes

Above parameters are measured at their recommended operation voltage and 20 °C.



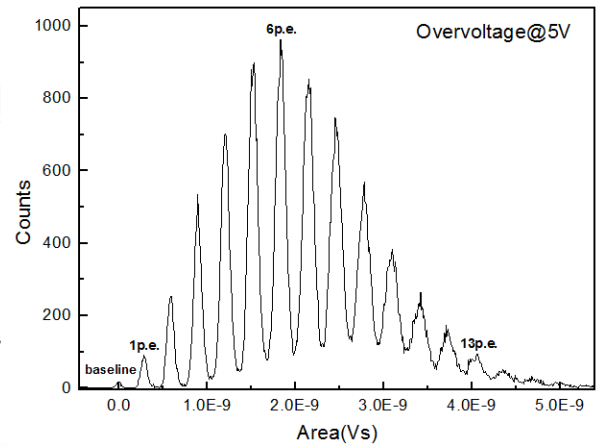
Characteristics of PSS 11-3030-S

Position Algorithm

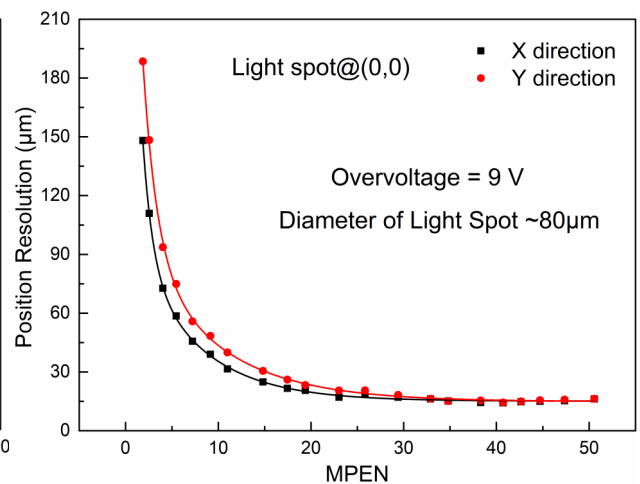
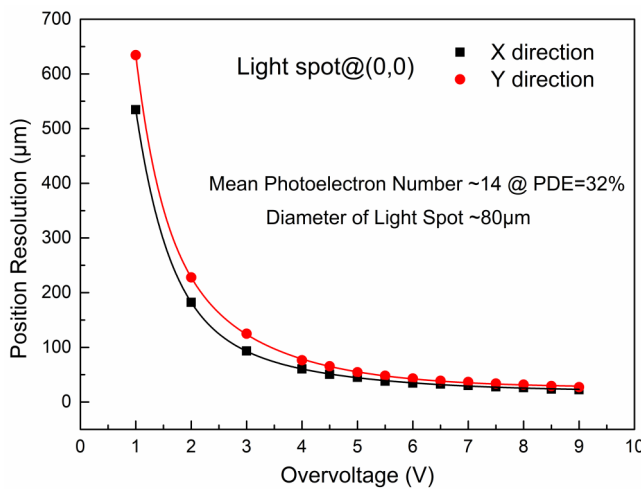
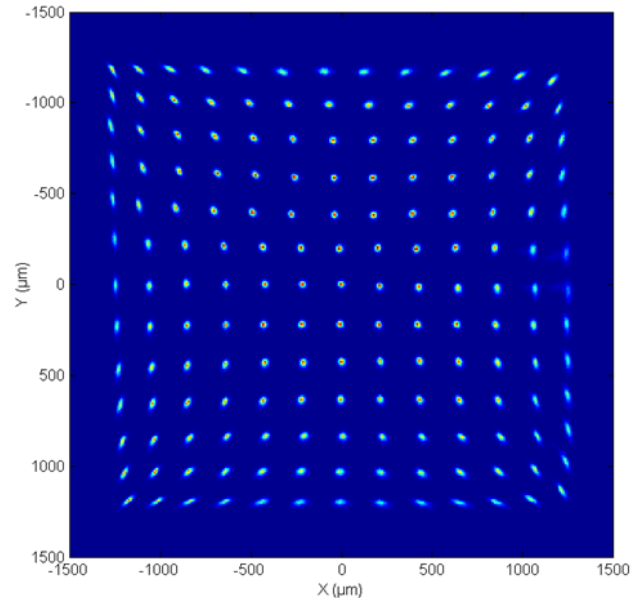
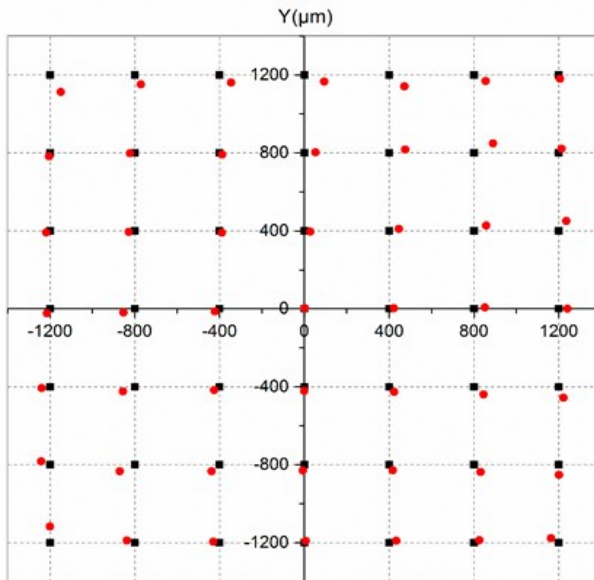
$$x_c = \frac{L}{2} \cdot \frac{\left(\frac{R_0}{R_s} + 8.7492\right)(Q_4 - Q_3) \left[\left(\frac{1.7R_0}{R_s} + 5.8156\right)(Q_1 + Q_2) + \left(\frac{R_0}{R_s} - 5.8156\right)(Q_3 + Q_4) \right]}{\left[\frac{R_0}{R_s}(Q_1 + Q_2 + Q_3 + Q_4) \right]^2 - \left[1.02 \left(\frac{R_0}{R_s} + 8.7492\right)(Q_2 - Q_1) \right]^2}$$

$$y_c = \frac{L}{2} \cdot \frac{\left(\frac{R_0}{R_s} + 8.7492\right)(Q_2 - Q_1) \left[\left(\frac{R_0}{R_s} - 5.8156\right)(Q_1 + Q_2) + \left(\frac{1.7R_0}{R_s} + 5.8156\right)(Q_3 + Q_4) \right]}{\left[\frac{R_0}{R_s}(Q_1 + Q_2 + Q_3 + Q_4) \right]^2 - \left[1.02 \left(\frac{R_0}{R_s} + 8.7492\right)(Q_4 - Q_3) \right]^2}$$

L is the length of the active area. R_0 is the sheet impedance, which is equal to 320Ω . R_s is the load impedance. Q_i ($i = 1, 2, 3, 4$) is the shared charge of the corresponding anode.



■ True light spot position ● Measured light spot position



Test Conditions: OV=9 V if not specified, Temp.=20 °C, Load Impedance = 50 Ω.



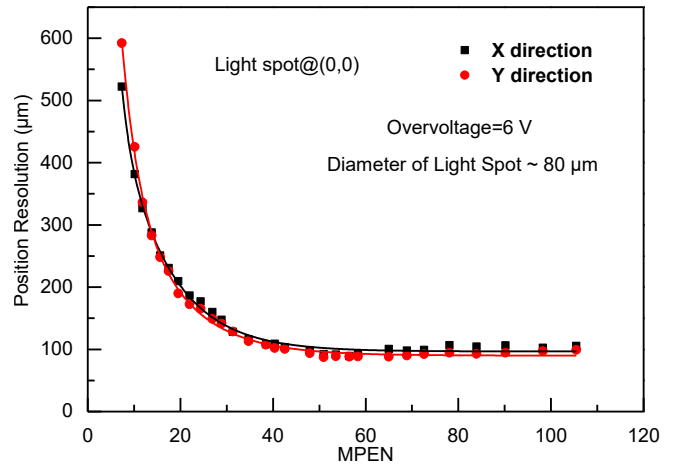
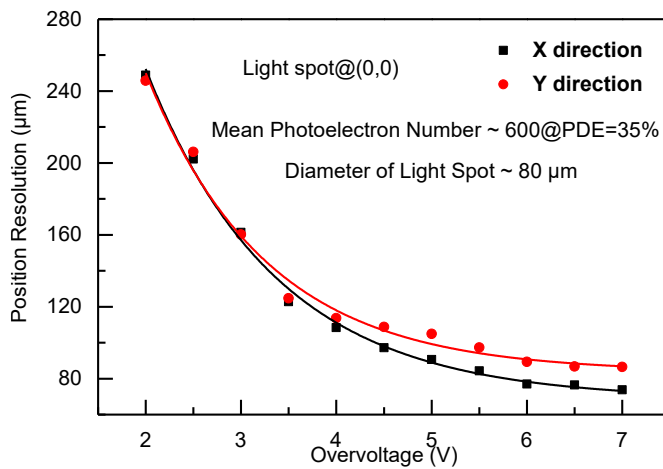
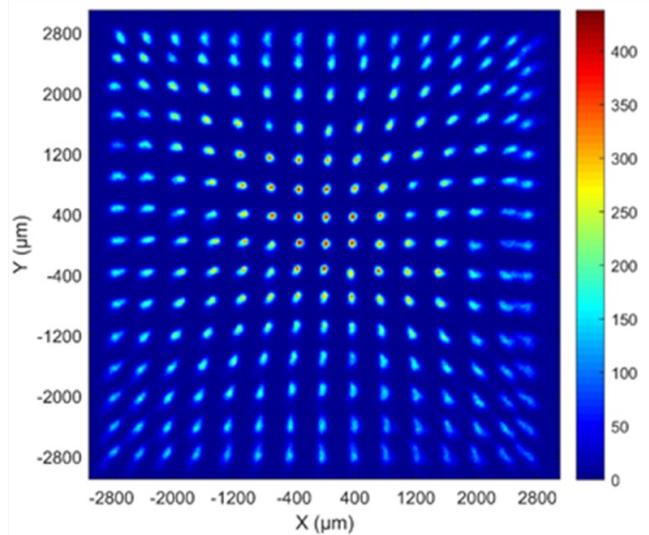
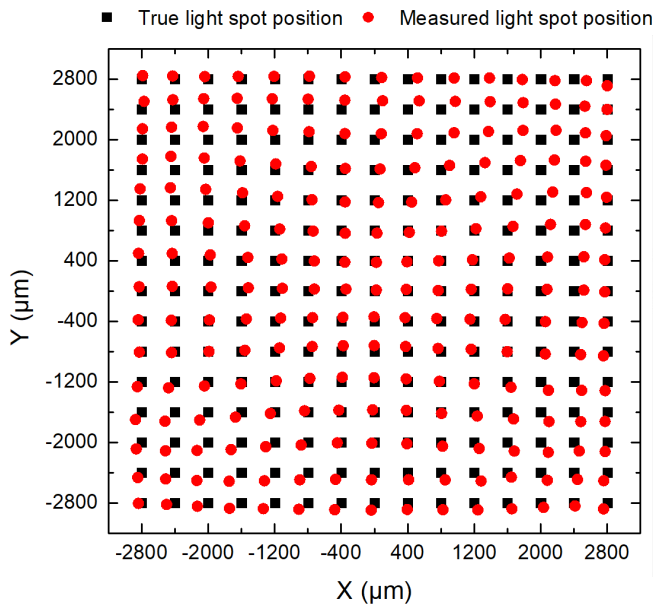
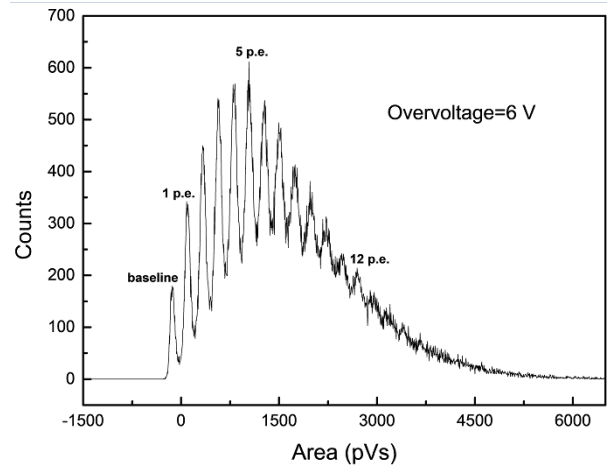
Characteristics of PSS 11-6060-S

Position Algorithm

$$x_c = \frac{L}{2} \cdot k \cdot \frac{(Q_2 + Q_3) - (Q_1 + Q_4)}{(Q_1 + Q_2 + Q_3 + Q_4)}$$

$$y_c = \frac{L}{2} \cdot k \cdot \frac{(Q_3 + Q_4) - (Q_1 + Q_2)}{(Q_1 + Q_2 + Q_3 + Q_4)}$$

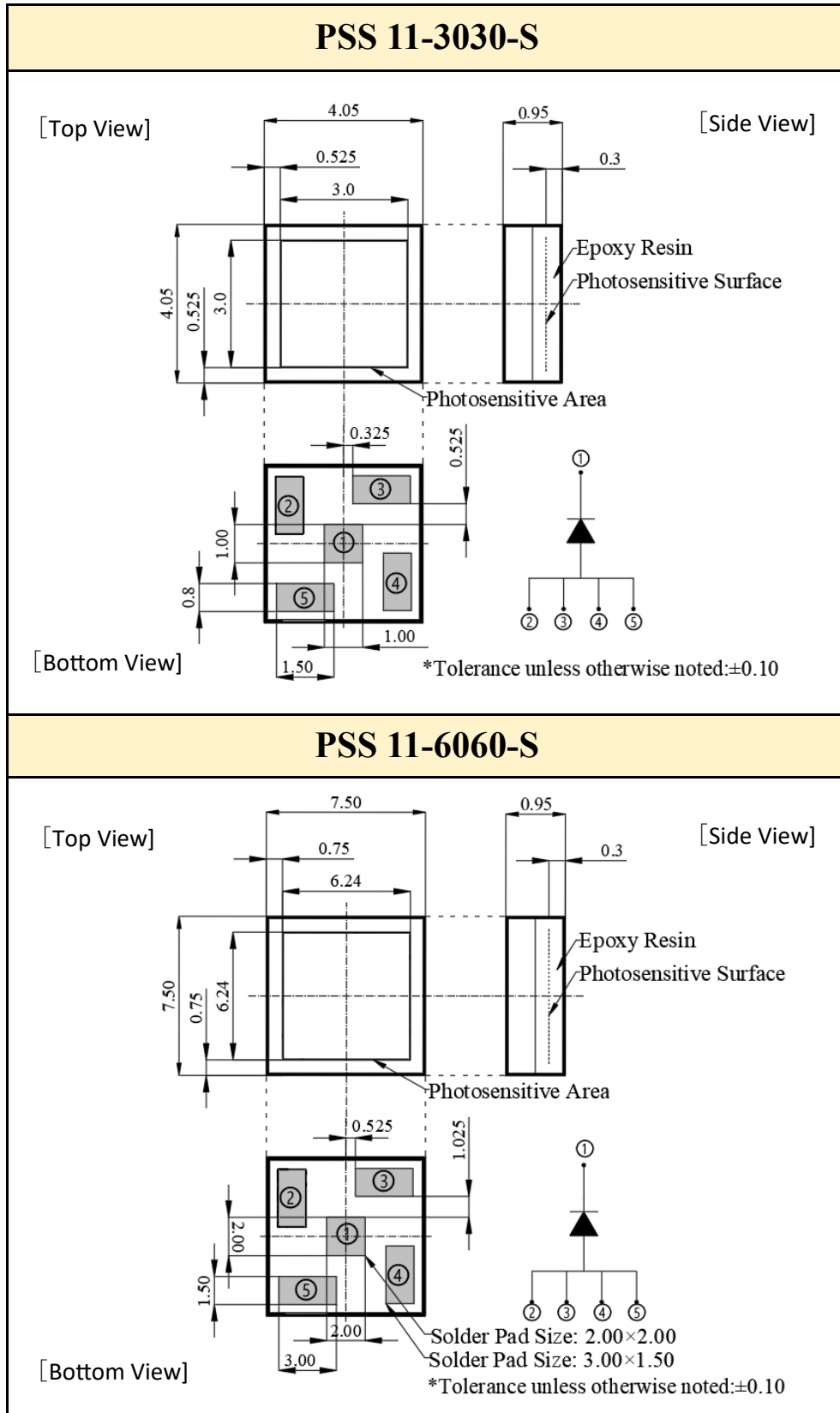
L is the length of the active area. Q_i ($i = 1, 2, 3, 4$) is the shared charge of the corresponding anode. k is the calibration factor.



Test Conditions: OV=6 V if not specified, Temp.=20 °C.

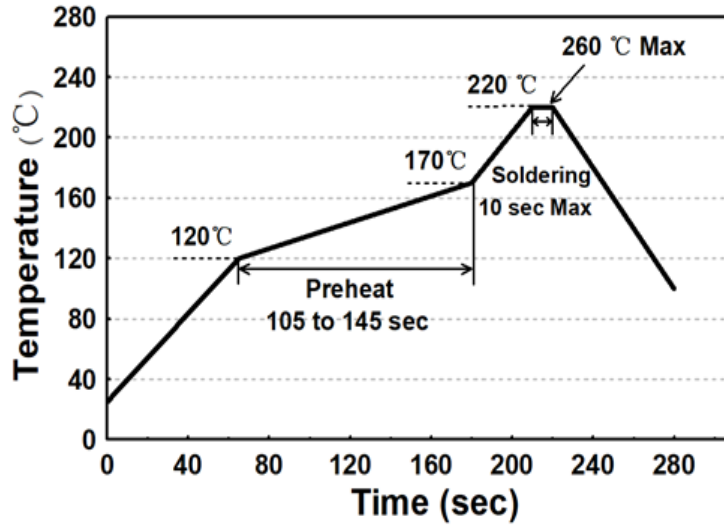


Dimensional outlines (unit: mm)





Recommended Solder Reflow Conditions



Basic Connection Diagrams

